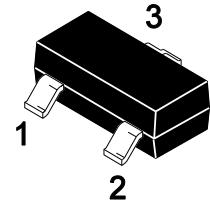


Features

- Glass Passivated Chip Junction
- Low forward voltage
- Fast reverse recovery time

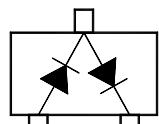
SOT-23



1.Anode1 2.Cathode2
3.Cathode1、Anode2

Equivalent Circuit

3.Cathode1、Anode2



1.Anode1 2.Cathode2

Marking Code : B2

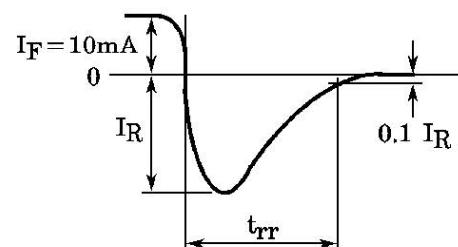
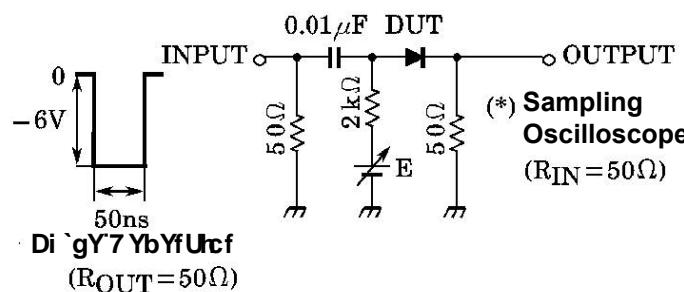
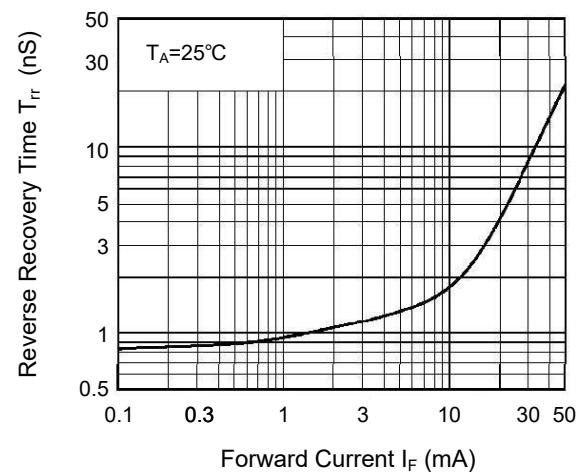
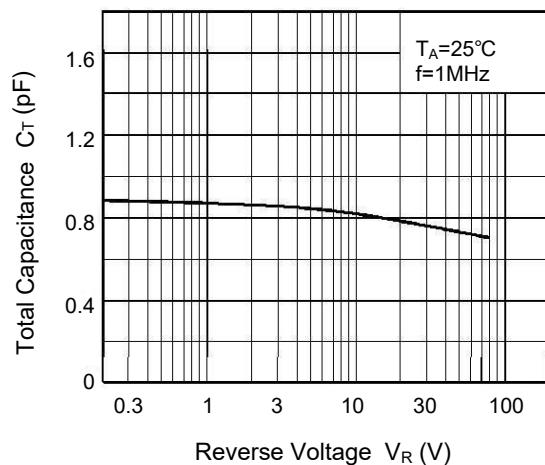
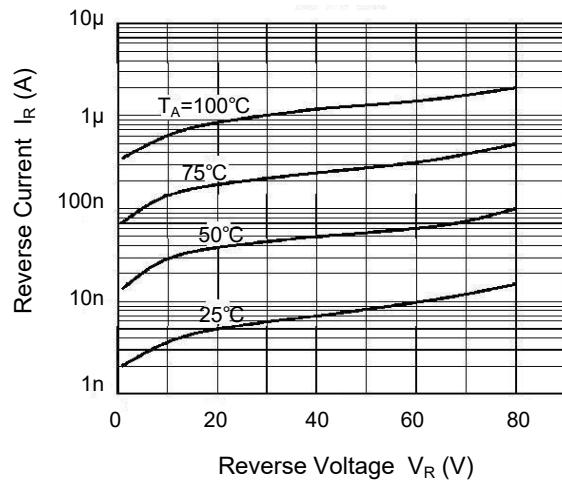
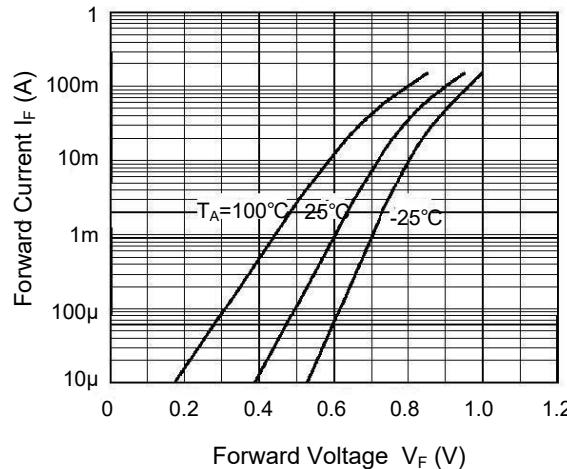
Absolute Maximum Ratings ($T_A=25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	85	V
Reverse Voltage	V_R	80	V
Average Rectified Forward Current	$I_{F(AV)}$	100	mA
Maximum Peak Forward Current	I_{FM}	300	mA
Non-Repetitive Peak Forward Surge Current at $t=10\text{ms}$	I_{FSM}	2	A
Maximum Power Dissipation	P_D	350	mW
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-50 to +150	$^\circ\text{C}$

Electrical Characteristics ($T_A=25^\circ\text{C}$)

Parameter	Symbol	Min.	Max.	Unit
Forward Voltage at $I_F = 100 \text{ mA}$	V_F	--	1.2	V
Reverse Current at $V_R = 80 \text{ V}$	I_R	--	0.5	μA
Typical Junction Capacitance at $V_R = 0 \text{ V}, f = 1 \text{ MHz}$	C_j	--	3	pF
Maximum Reverse Recovery Time at $I_F = 10 \text{ mA}$	T_{rr}	--	4	nS

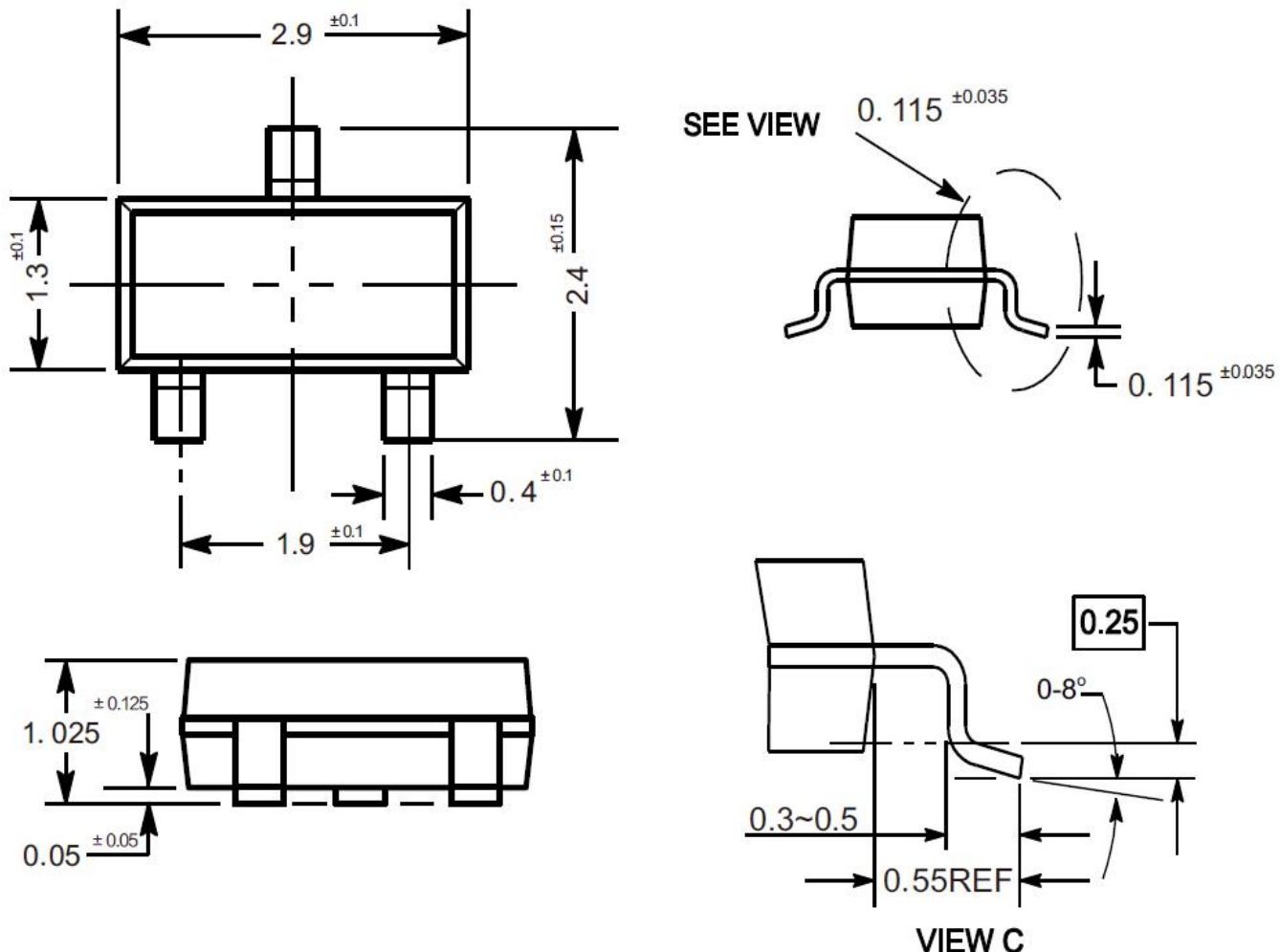
Typical Characteristic Curves



Package Outline

SOT-23

Dimensions in mm



Ordering Information

Device	Package	Shipping
1SS226	SOT-23	3,000PCS/Reel&7inches